## **Chapter 9**

## **Future Prospects**

For carbon nanotubes field emission displays' application, the further research topics are proposed as follows.

- Low temperature growth (below 450°C) of carbon nanotubes using binary alloys of Fe, Co, Ni, Pd, Cr....
- (2) Pre-treatments of metal catalyst before CNTs' growth for density control of carbon nanotubes. For example: partial oxidation of catalyst, laser pre-treatment.....
- (3) Post-treatment of carbon nanotubes such as other gas plasma post-treatment, laser irradiation and rapid thermal annealing to reduce the density of carbon nanotubes.
- (4) Post-treatment of carbon nanotubes to improve the crystallization of carbon nanotubes grown under low temperature.
- (5) Nano-imprint of well crystallization carbon nanotubes to avoid direct low temperature growth of carbon nanotubes.
- (6) Demonstration of a diode/triode field emission display of small dimension.
- (7) Explore the technologies of CNTs backlight unit.

For the applications in vacuum microelectronics, the further research topics are proposed as follows.

(1) Fabrication of CNTs lateral field emission diode/triode for high frequency and

high power circuit applications.

- (2) Vacuum sealed of LFED for practical application.
- (3) Fabrication of CNTs gas sensor.

For the applications of CNTs in nano-electronis, the further research topics are proposed as follows.

- (1) Find the stable growth process for high yield growth of single wall carbon nanotubes (SWNT).
- (2) Find the growth condition of real lateral growth of SWNT.
- (3) Fabrication of CNTFET.

